



Ultrafast Inorganic Scintillator Based Front Imager for GHz Hard X-Ray Imaging

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for

The Ultrafast Materials and Application Collaboration

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The Ultrafast Materials and Applications (UMA) Collaborators

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A beam test carried out at the APS 10-ID site on July 2 -3, 2018 See reports by Junqi Xie, Xuan Li and Thomas Smith in this conference



High-Energy and Ultrafast X-Ray Imaging Technologies and Applications

Organizers: Peter Denes, Sol Gruner, Michael Stevens & Zhehui (Jeff) Wang¹ (Location/Time: Santa Fe, NM, USA /Aug 2-3, 2016)

The goals of this workshop are to gather the leading experts in the related fields, to prioritize tasks for ultrafast hard X-ray imaging detector technology development and applications in the next 5 to 10 years, see Table 1, and to establish the foundations for near-term R&D collaborations.

Performance	Type I imager	Type II imager		
X-ray energy	30 keV	42-126 keV		
Frame-rate/inter-frame time	🗾 0.5 GHz/2 ns	3 GHz / 300 ps		
Number of frames	10	10 - 30		
X-ray detection efficiency	above 50%	above 80%		
Pixel size/pitch	≤ 300 μm	< 300 μm		
Dynamic range	10 ³ X-ray photons	≥ 10 ⁴ X-ray photons		
Pixel format	64 x 64 (scalable to 1 Mpix)	1 Mpix		

Table I. High-energy photon imagers for MaRIE XFEL

2 ns and 300 ps inter-frame time requires ultrafast sensor



Scintillator Based Front Imager



- BaF₂ has good efficiency for hard X-rays. Its fast scintillation with sub-ns decay time provides bright light in 1st ns with very little tail.
- Yttrium doping in BaF₂ suppresses its slow scintillation significantly and maintains its fast light.
- A detector concept:
 - Pixelized ultrafast crystal screen;
 - Pixelized ultrafast photodetector;
 - Fast electronics readout.
- Discussed in this report: Fast Scintillator Ultrafast crystals and photodetectors.

Fast Electronics

Photo

Detectors



12 Fast Inorganic Scintillators



	BaF ₂	BaF ₂ (:Y)	ZnO (:Ga)	YAP (:Yb)	YAG (:Yb)	β- Ga₂O₃	LYSO (:Ce)	LuAG (:Ce)	YAP (:Ce)	GAGG (:Ce)	LuYAP (:Ce)	YSO (:Ce)
Density (g/cm ³)	4.89	4.89	5.67	5.35	4.56	5.94 ^[1]	7.4	6.76	5.35	6.5	7.2 ^f	4.44
Melting points (°C)	1280	1280	1975	1870	1940	1725	2050	2060	1870	1850	1930	2070
X _o (cm)	2.03	2.03	2.51	2.77	3.53	2.51	1.14	1.45	2.77	1.63	1.37	3.10
R _M (cm)	3.1	3.1	2.28	2.4	2.76	2.20	2.07	2.15	2.4	2.20	2.01	2.93
λ _ι (cm)	30.7	30.7	22.2	22.4	25.2	20.9	20.9	20.6	22.4	21.5	19.5	27.8
Z _{eff}	51.6	51.6	27.7	31.9	30	28.1	64.8	60.3	31.9	51.8	58.6	33.3
dE/dX (MeV/cm)	6.52	6.52	8.42	8.05	7.01	8.82	9.55	9.22	8.05	8.96	9.82	6.57
λ _{peak} ª (nm)	300 220	300 220	380	350	350	380	420	520	370	540	385	420
Refractive Index ^b	1.50	1.50	2.1	1.96	1.87	1.97	1.82	1.84	1.96	1.92	1.94	1.78
Normalized Light Yield ^{a,c}	42 4.8	1.7 4.8	6.6 ^d	0.19 ^d	0.36 ^d	6.5 0.5	100	35° 48°	9 32	115	16 15	80
Total Light yield (ph/MeV)	13,000	2,000	2,000 ^d	57 ^d	110 ^d	2,100	30,000	25,000 ^e	12,000	34,400	10,000	24,000
Decay time ^a (ns)	600 <mark>0.6</mark>	600 <mark>0.6</mark>	<1	1.5	4	148 <mark>6</mark>	40	820 50	191 25	53	1485 36	75
LY in 1 st ns (photons/MeV)	1200	1200	610 ^d	28 ^d	24 ^d	43	740	240	391	640	125	318
40 keV Att. Leng. (1/e, mm)	0.106	0.106	0.407	0.314	0.439	0.394	0.185	0.251	0.314	0.319	0.214	0.334

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Fast Inorganic Scintillators



- [1] S. Geller, J. Chem. Phys. 1960, 33: 676.
- a. Top line: slow component, bottom line: fast component;
- b. At the wavelength of the emission maximum;
- c. Excited by Gamma rays;
- d. Excited by Alpha particles.
- e. Ceramic with 0.3 Mg at% co-doping
- f. Based on Lu_{0.7}Y_{0.3}AlO₃:Ce



12 Samples Tested with X-Rays



Scintillators with ultrafast decay time



Scintillators with fast decay time





APS Hybrid Beam Characteristics



https://ops.aps.anl.gov/SRparameters/node5.html

Singlet (16 mA, 50 ps) isolated from 8 septuplets (88 mA) with 1.594 μs gap. 8 septuplets (88 mA) with a period of 68 ns and a gap of 51 ns. Each septuplet of 17 ns consists of 7 bunches (27 ps) and 2.83 ns apart. Total beam current: 102 mA, rate: 270 kHz, period: 3.7 μs.





Photos Taken During Beam Test at APS 10-ID Site (July 2 -3, 2018)





APS 10-ID Site





The Test Setup at APS

Crystals, MCP-PMT and gate unit were in the hutch at APS 10-ID site. Tektronix DPO71254C, delay unit and HV supplier were in the control room. Signal from MCP-PMT went through a 15 m wideband SMA cable, which compromises PMT's temporal response.



Ultrafast Photodetectors





Photek MCP-PMT 110 and 210 are ultrafast

STITUTEOR

, Chicago

Hybrid Beam Measured by BaF₂:Y

Data taken with Photek PMT & gate unit for septuplet bunches show crystal's capability for hard X-ray imaging with 2.83 ns bunch spacing.

Data were also taken for singlet bunches to show crystal's temporal response.







Septuplet X-ray Imaging



Clear septuplet structure observed by BaF₂:Y, BaF₂ and ZnO:Ga, but not by LYSO:Ce and other crystals with long decay time



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2.83 ns X-ray Bunch Imaging by BaF₂



X-ray bunches with 2.83 ns spacing in septuplet are clearly resolved by ultrafast BaF₂ crystals, showing a proof-of-principle for the MaRIE type –l imager.





Fitting Temporal Response



Rise time, decay time and FWHM pulse width are estimated by a simple fitting with two exponential components



Fitting:

$$\mathsf{V} = A(e^{-\frac{t}{\tau_d}} - e^{-\frac{t}{\tau_r}}) + \mathsf{B}$$

A: amplitude,
B: background noise or slow component,
τ_r: rise time,
τ_d: decay time.

> Sub-ns pulse observed by Photek MCP-PMT 240 for Cherenkov light



Singlet Bunch by Ultrafast Crystals



Peak amplitude of BaF_2 and BaF_2 :Y higher than ZnO:Ga and LYSO Rise/decay time of BaF_2 and BaF_2 :Y shorter than ZnO:Ga and LYSO



Rise/decay time of BaF_2 and BaF_2 : Y longer than the γ -ray source data measured at Caltech because of the 15 m cable length

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Temporal Response of BaF₂:Y



Significantly slower responses observed at APS with a 15 m cable as compared to pulses measured with a 1 m cable at Caltech

Caltech Data

APS Data





Singlet Bunches by Ultrafast Crystals





BaF₂:Y and BaF₂ show ultrafast temporal response.

YAP:Yb, ZnO:Ga and YAG:Yb show slower response.



Singlet Bunches by Fast Crystals



Decay time consists with Lab data measured with source



All fast crystals are too slow for GHz X-ray imaging



Summary: Temporal Response



Crystal	Vendor	ID	Dimension (mm³)	Emission Peak (nm)	EWLT (%)	LO (p.e./MeV)	Light Yield in 1 st ns (ph/MeV)	Rising Time (ns)	Decay Time (ns)	FWHM (ns)
BaF ₂ :Y	SIC	4	10×10×5	220	89.1	258	1200	0.2	1.0	1.4
BaF ₂	SIC	1	50×50×5	220	85.1	209	1200	0.2	1.2	1.5
YAP:Yb	Dongjun	2-2	Ф40×2	350	77.7	9.1*	28	0.4	1.1	1.7
ZnO:Ga	FJIRSM	2014-1	33×30×2	380	7	76*	157	0.4	1.8	2.3
YAG:Yb	Dongjun	4	10×10×5	350	83.1	28.4*	24	0.3	2.5	2.7
Ga ₂ O ₃	Tongji	2	7x7x2	380	73.8	259	43	0.2	5.3	7.8
YAP:Ce	Dongjun	2102	Ф50×2	370	54.7	1605	391	0.8	34	27
LYSO:Ce	SIC	150210-1	19x19×2	420	80.1	4841	740	0.7	36	28
LuYAP:Ce	SIPAT	1	10×10×7	385	١	1178	125	1.1	36	29
LuAG:Ce Ceramic	SIC	S2	25×25×0.4	520	52.3	1531	240	0.6	50	40
YSO:Ce	SIC	51	25×25×5	420	72.6	3906	318	2.0	84	67
GAGG:Ce	SIPAT	5	10×10×7	540	١	3212	239	0.9	125	91

Samples are ordered based on its FWHM to singlet bunches

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Photodetector and Cable Length



- Significantly slower temporal responses observed in the APS data taken with a 15 m cable and a gate unit as compared to the Caltech data taken with an 1 m cable without gate unit.
- Temporal responses of various photodetectors to 40 ps laser pulses from an Advanced Laser Diode PiL037X at 373 nm were measured at Caltech after the APS beam test with both 1 and 15 m cables connected to the Tektronix DPO71254C scope (12.5 GHz, 100 GS/s) used in the beam test with and without the gate unit.
- Temporal responses of Cherenkov light from PbF₂ and scintillation light from BaF₂ were measured at Caltech by the Photek PMT 210 for both 1 and 15 m cables, and compared to the Caltech and APS data with 240, respectively.



Test Setup for Photo-detectors





Photek PMT110: Laser Diode

Pulse shape measured with 1 m cable consists with the Photek data Pulse width measured with 15 m cable is broadened from 0.20 to 0.53 ns





PMT110: Laser Diode & Gate Unit



The gate unit GM10-50B does not change pulse shape

15 m cable 1 m cable 2500 700 Pulsed laser (PiL037X), 40 ps (FWHM), 373 nm Pulsed laser (PiL037X), 40 ps (FWHM), 373 nm Photek MCP-PMT110, HV=-4800V, 1 m cable Gate unit GM10-50B, 500 ns gate Photek MCP-PMT110, HV=-4800V, 15 m cable 2250 Gate unit GM10-50B, 500 ns gate 600 Tektronix DP071254C (12.5 GHz, 100 GS/s) Tektronix DPO71254C (12.5 GHz, 100 GS/s 2000 500 1750 ()1500 1250 1000 Voltage (mV) 005 007 $\tau_r = 0.07 \pm 0.01 \text{ ns}$ $\tau_r = 0.11 \pm 0.02$ hs $\tau_{d} = 0.08 \pm 0.02$ ns $\tau_{\rm d} = 0.36 \pm 0.03$ ns FWHM = 0.20 + 0.04 ns FWHM = 0.52 ± 0.05 ns 750 200 500 100 250 -0.5 -0.25 0 0 0.25 0.5 0.75 1.25 1.5 1.75 2 1 -1 0 2 6 Time (ns) Time (ns)



Photek PMT210: Laser Diode

Pulse shape measured with 1 m cable consists with the Photek data Pulse width measured with 15 m cable is broadened from 0.26 to 0.67 ns





PMT210: Laser Diode & Gate Unit



The gate unit GM10-50B does not change pulse shape

15 m cable

1 m cable





Hamamatsu R3809U: Laser Diode



Pulse shape measured with 1 m cable consists with the Hamamatsu data Pulse width measured with 15 m cable is broadened from 0.32 to 0.68 ns

1 m cable

15 m cable





Hamamatsu R2059: Laser Diode

1.3 ns rise time measured with 1 m cable consists with Hamamatsu data 15 m cable has a minor effect on the pulse shape compared to 1 m cable





All Photodetectors: Laser Diode



15 m cable slows down ultrafast photo-detector response significantly

Photodetector	Dimensions	Mode	Cable (m)	τ _r (ns)	τ _d (ns)	FWHM (ns)
Photek MCP-PMT110	Ф10 mm	DC	1	0.07±0.01	0.08±0.02	0.20±0.04
Photek MCP-PMT110	Φ10 mm	Gate (500 ns)	1	0.07±0.01	0.08±0.02	0.20±0.04
Photek MCP-PMT210	Φ10 mm	DC	1	0.09±0.02	0.11±0.02	0.26±0.05
Photek MCP-PMT210	Φ10 mm	Gate (500 ns)	1	0.09±0.02	0.12±0.02	0.27±0.05
Hamamatsu MCP-PMT U3809U	Φ11 mm	DC	1	0.12±0.02	0.14±0.02	0.32±0.05
Hamamatsu PMT R2059	Φ50 mm	DC	1	1.21±0.05	1.26±0.05	3.0±0.1
Photek MCP-PMT110	Φ10 mm	DC	15	0.11±0.02	0.37±0.03	0.53±0.05
Photek MCP-PMT110	Φ10 mm	Gate (500 ns)	15	0.11±0.02	0.36±0.03	0.52±0.05
Photek MCP-PMT210	Φ10 mm	DC	15	0.15±0.02	0.46±0.04	0.67±0.05
Photek MCP-PMT210	Φ10 mm	Gate (500 ns)	15	0.15±0.02	0.44±0.03	0.66±0.05
Hamamatsu MCP-PMT U3809U	Φ11 mm	DC	15	0.27±0.02	0.28±0.03	0.68±0.05
Hamamatsu PMT R2059	Φ50 mm	DC	15	1.35±0.05	1.36±0.05	3.3±0.1











Cerenkov: 5 cm PbF₂ Cube



PMT 210 + 1 m cable: Cherenkov consists with the 40 ps laser PMT210 + 15 m cable: significantly slower pulse shape

1 m cable



15 m cable





Scintillation: BaF₂-Y-54



PMT 210 + 1 m cable: scintillation consists with the PMT 240 data PMT 210 + 15 m cable: scintillation consists with the APS data





Summary



- Test beam data for septuplet bunches with 2.83 ns spacing at the APS 10-ID beam site show clearly separated X-ray pulses observed by ultrafast inorganic scintillators, such as BaF₂:Y, coupled to ultrafast photodetectors, such as Photek MCP-PMT, demonstrating feasibility of an ultrafast scintillator based front imager for GHz hard X-ray imaging. YAP:Yb, ZnO:Ga and YAG:Yb are slower.
- Temporal response of BaF₂ shows the highest amplitude, fastest response among a dozen fast inorganic scintillators. With suppressed slow component, response of BaF₂:Y shows no pile-up for 8 septuplet bunches with 2.83 ns spacing.
- Temporal responses of BaF₂ crystals measured by Photek MCP-PMTs with 1 and 15 m cable confirm that the 1.5 ns pulse width observed at APS is caused by the 15 m cable length. It is crucial to keep all connections short in the ultrafast front imager design.

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